## Slotted Optical Switch OPB818

## Features:

- Choice of aperture
- Choice of opaque or IR transmissive shell material
- Non-contact switching
- Mounts directly to PCBoard or dual-in-line socket
- 0.400 " ( 10.16 mm ) lead spacing
$\bullet 0.200 "(5.08 \mathrm{~mm})$ slot width. 0.250 " $(6.35 \mathrm{~mm})$ slot depth


## Description:

The OPB818 slotted switch consists of an infrared emitting diode and an NPN silicon phototransistor mounted in a low-cost black plastic housing on opposite sides of a $0.200 "(5.080 \mathrm{~mm})$ wide slot. Switching of the phototransistor occurs whenever an opaque object passes through the slot.

The OPB818Z is designed for direct soldering into PCBoards or for mounting in standard dual-in-line sockets and has an 0.25 " ( 6.35 mm ) deep and $0.20^{\prime \prime}(5.08 \mathrm{~mm})$ wide slot. The apertures are 0.06 " ( 1.52 mm ) in diameter on both the sensor side (" S ") as well as on the emitter side (" E ").

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information.

## Applications:

- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety


| Pin \# | Description | Pin \# | Description |
| :---: | :---: | :---: | :---: |
| 1 | Anode | 3 | Collector |
| 2 | Cathode | 4 | Emitter |



| Ordering Information |  |
| :---: | :---: |
| Part <br> Number | Description |
| OPB818 | Slotted Optical Switch <br> (mounts directly to PCBoards <br> or to dual-in-line socket) |

[^0]OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

## Slotted Optical Switch OPB818

## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Storage \& Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Lead Soldering Temperature [1/16 inch $(1.6 \mathrm{~mm})$ from the case for 5 sec . with soldering iron ${ }^{(1)}$ | $260^{\circ} \mathrm{C}$ |

## Input Diode

| Forward DC Current | 50 mA |
| :--- | ---: |
| Peak Forward Current $(1 \mu \mathrm{~s}$ pulse width, 300 pps$)$ | 3 A |
| Reverse DC Voltage | 2 V |
| Power Dissipation ${ }^{(2)}$ | 100 mW |

Output Phototransistor

| Collector-Emitter Voltage | 30 V |
| :--- | ---: |
| Emitter-Collector Voltage | 5 V |
| Collector DC Current | 30 mA |
| Power Dissipation ${ }^{(2)}$ | 100 mW |

Electrical Characteristics $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |

Input Diode (see OP240 for additional information)

| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage | - | - | 1.7 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| :--- | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | - | - | 100 | $\mu \mathrm{~A}$ | $\mathrm{~V}_{\mathrm{R}}=2 \mathrm{~V}$ |

Output Phototransistor (see OP550 for additional information)

| $\mathrm{V}_{\text {(BR)(CEO) }}$ | Collector-Emitter Breakdown Voltage | 30 | - | - | V | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{~V}_{\text {(BR)(ECO) }}$ | Emitter-Collector Breakdown Voltage | 5 | - | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| $\mathrm{I}_{\mathrm{CEO}}$ | Collector-Emitter Leakage Current | - | - | 100 | nA | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \mathrm{E}_{\mathrm{E}}=0$ |

Coupled

| $\mathrm{I}_{\mathrm{C}(\mathrm{ON})}$ | On-State Collector Current | 100 | - | - | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{~V}_{\mathrm{CE}(\mathrm{SAT})}$ | Collector-Emitter Saturation Voltage | - | - | 0.4 | V | $\mathrm{I}_{\mathrm{C}}=50 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |

Notes:
(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
(2) Derate linearly $1.67 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(3) All parameters were tested using pulse techniques.
(4) Leads are $0.20^{\prime \prime}$ square ( 5.080 mm ) and $0.425^{\prime \prime}$ long ( 10.80 mm ), minimum.
(5) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones. Spray and wipe; do not submerge.
(6) Polarity is denoted by color of housing top: LED (gray or clear), sensor (black).



[^0]:    RoHS

